

●Applications

General purpose small signal amplifier

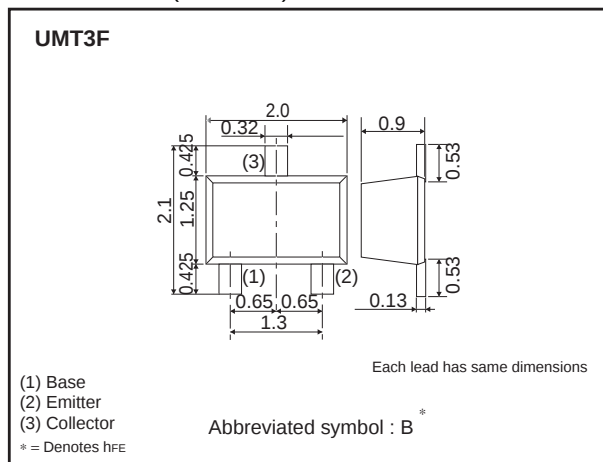
●Features

- 1) Low Cob.
Cob=2.0pF (Typ.)
- 2) Complements the 2SA1576UB.

●Structure

NPN silicon epitaxial planar transistor

●Dimensions (Unit : mm)



●Absolute maximum (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	60	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	7	V
Collector current	I _c	150	mA
	I _{CP} *1	200	mA
Power dissipation	P _D *2	200	mW
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

*1 Pw=1ms Single pulse

*2 Each terminal mounted on a recommended land

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV _{CEO}	50	—	—	V	I _c =1mA
Collector-base breakdown voltage	BV _{CB0}	60	—	—	V	I _c =50μA
Emitter-base breakdown voltage	BV _{EBO}	7	—	—	V	I _E =50μA
Collector cutoff current	I _{CB0}	—	—	100	nA	V _{CB} =60V
Emitter cutoff current	I _{EBO}	—	—	100	nA	V _{EB} =7V
Collector-emitter saturation voltage	V _{CE(sat)}	—	—	400	mV	I _c /I _B =50mA/5mA
DC current gain	h _{FE}	120	—	560	—	V _{CE} =6V, I _c =1mA
Transition frequency	f _T	—	180	—	MHz	V _{CE} =12V, I _E =-2mA, f=100MHz
Output capacitance	Cob	—	2.0	3.5	pF	V _{CB} =12V, I _E =0A, f=1MHz

h_{FE} rank categories

Rank	Q	R	S
h _{FE}	120 to 270	180 to 390	270 to 560

●Electrical characteristic curves

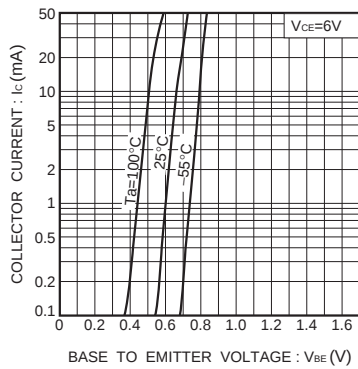


Fig.1 Grounded emitter propagation characteristics

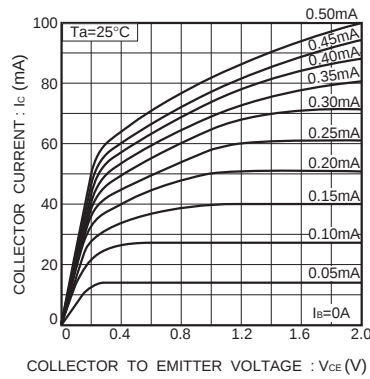


Fig.2 Grounded emitter output characteristics (I)

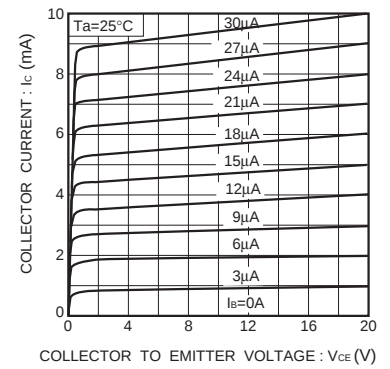


Fig.3 Grounded emitter output characteristics (II)

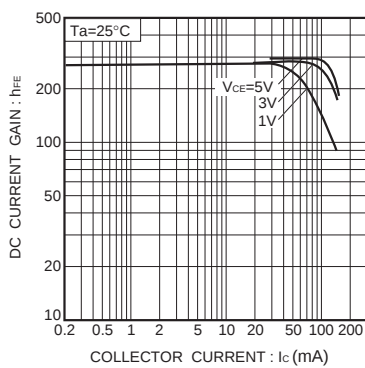


Fig.4 DC current gain vs. collector current (I)

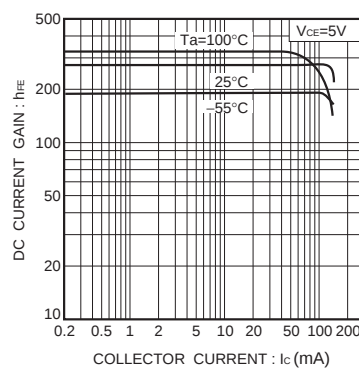


Fig.5 DC current gain vs. collector current (II)

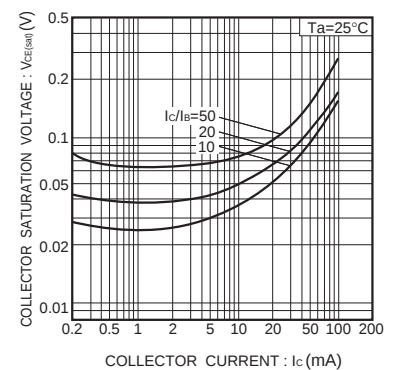


Fig.6 Collector-emitter saturation voltage vs. collector current

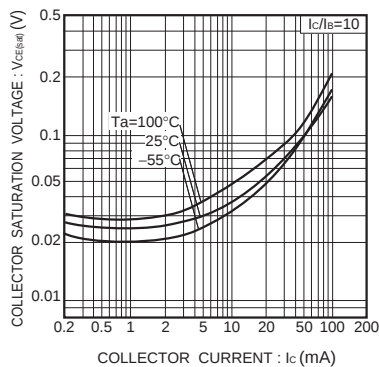


Fig.7 Collector-emitter saturation voltage vs. collector current (I)

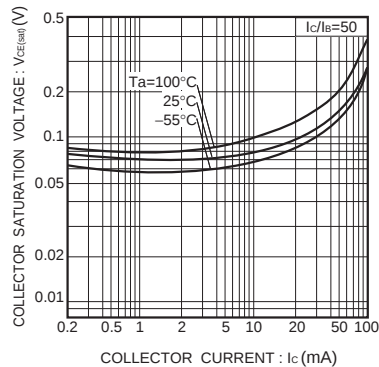


Fig.8 Collector-emitter saturation voltage vs. collector current (II)

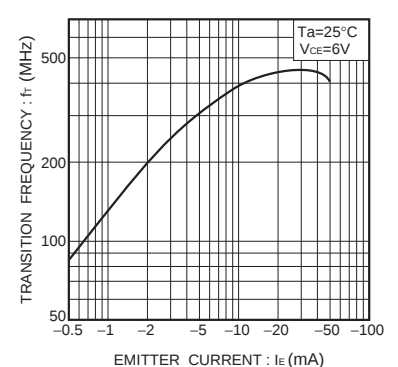


Fig.9 Gain bandwidth product vs. emitter current

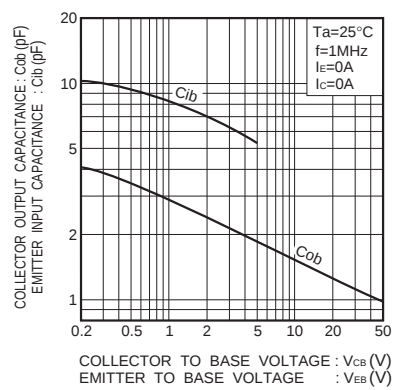


Fig.10 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

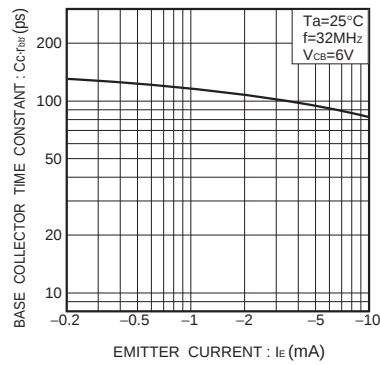


Fig.11 Base-collector time constant vs. emitter current

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